Unit in mm

TOSHIBA Field Effect Transistor Silicon P Channel Mos Type

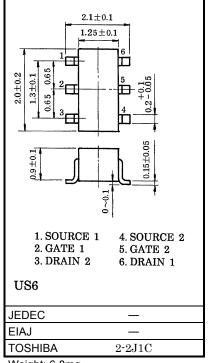
HN1J02FU

High Speed Switching Applications Analog Switch Applications

- High input impedance
- Low threshold voltage: V_{th} =−0.5V~−1.5V
- High speed
- Small package

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	-20	V
Gate-source voltage	V _{GSS}	-7	V
DC drain current	I _D	-50	mA
Drain power dissipation	P _D *	200	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C



Weight: 6.8mg

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

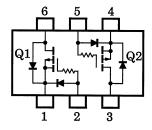
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

* Total rating

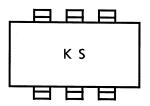
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	_	V _{GS} = -7V, V _{DS} = 0	_	_	-1	μΑ
Drain-source breakdown voltage		V (BR) DSS	_	I _D = -100μA, V _{GS} = 0	-20	_	_	V
Drain cut-off current		I _{DSS}	_	V _{DS} = -20V, V _{GS} = 0	_	_	-1	μΑ
Gate threshold voltage		V _{th}	_	$V_{DS} = -3V$, $I_D = -0.1mA$	-0.5	_	-1.5	V
Forward transfer admittance		Y _{fs}	_	V _{DS} = -3V, I _D = -10mA	15	_	_	mS
Drain-source ON resistance		R _{DS} (ON)	_	$I_D = -10$ mA, $V_{GS} = -2.5$ V	_	20	40	Ω
Input capacitance		C _{iss}	_	$V_{DS} = -3V$, $V_{GS} = 0$, $f = 1MHz$	_	10.4	_	pF
Reverse transfer capacitance		C _{rss}	_	$V_{DS} = -3V$, $V_{GS} = 0$, $f = 1MHz$	_	2.8	_	pF
Output capacitance		C _{oss}	_	$V_{DS} = -3V$, $V_{GS} = 0$, $f = 1MHz$	_	8.4	_	pF
Switching time	Turn-on time	t _{on}	_	V _{DD} = -3V, I _D = -10mA, V _{GS} = 0~-2.5V	_	0.15	_	μs
	Turn-off time	t _{off}	_	V _{DD} = -3V, I _D = -10mA, V _{GS} = 0~-2.5V	_	0.13	_	μs

Equivalent Circuit (Top View)

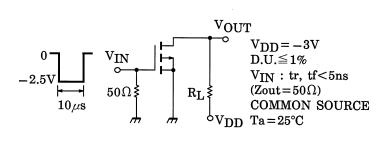


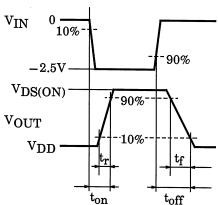
Marking

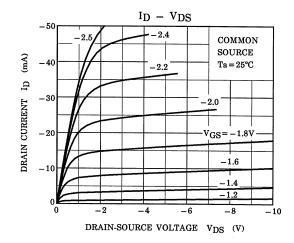


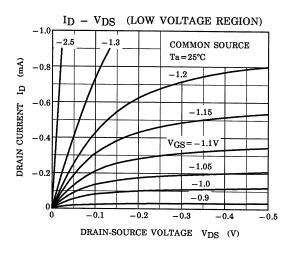
(Q1,Q2 Common)

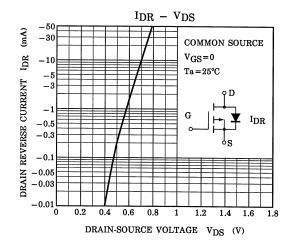
Switching Time Test Circuit

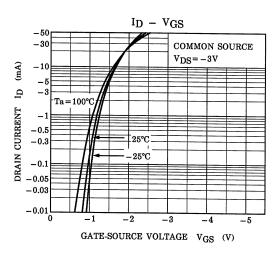






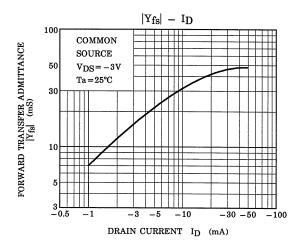


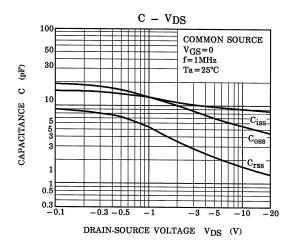


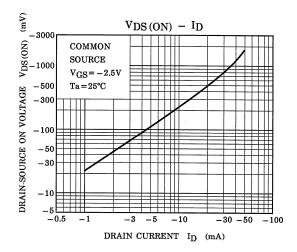


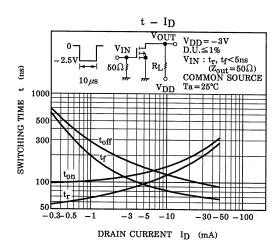
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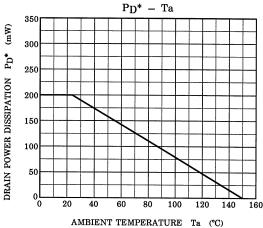
(Q1,Q2 Common)











* : Total Rating

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20070701-EN GENERAL

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